



IFU

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:	§	Attorney Docket No.
Chen-Bau WU, et al.	§	24061.148 (TSMC2003-0893)
	§	Customer No. 42717
Serial No.: 10/821,432	§	
	§	Group Art Unit: 2815
Filed: April 9, 2004	§	
	§	Examiner: Budd, Paul A
For: A HIGH VOLTAGE	§	
SEMICONDUCTOR DEVICE	§	
UTILIZING A DEEP TRENCH	§	
STRUCTURE	§	

AMENDMENT

Mail Stop Amendment
Commissioner of Patents
P. O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

I. Introductory Comments

The present paper is being submitted in response to the Office Action mailed August 25, 2005. The accompanying amendments and remarks are responsive to the Office Action.

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 3 of this paper.

Remarks begin on page 13 of this paper.